Seat No.: Enrolment No GUJARAT TECHNOLOGICAL UNIVERSITY BE SEM-V Examination-Nov/Dec2011			
Subject code: 151703 Date: 29/11/201			
•		ame: Electronics in Industries	
Ū		Time: 2.30 Total mark	pm -5.00 pm
Instru	ction		29. 70
		empt all questions.	
		ke suitable assumptions wherever necessary.	
3. Q.1		Ires to the right indicate full marks. Explain the turn-on and turn-off characteristics of an SCR.	07
Q.1	(b)	Explain the constructional details working and characteristics of an SCR.	07
Q.2	(a)	How does a GTO differ from a conventional thyristor? Explain its working and discuss merits and demerits over a conventional thyrisor.	07
	(b)	Give a cross-sectional view of a TRIAC and explain its different modes of operation. OR	07
	(b)	What is the difference between an enhancement type MOSFET and depletion type MOSFET and explain the working of an enhancement type power MOSFET.	07
Q.3	(a)	What do you mean by commutation? Discuss the methods of commutation of thyristor.	07
	(b)	Explain the working of UJT relaxation oscillator. How can synchronization with the mains supply be made? OR	07
Q.3	(a)	Discuss the Overcurrent protection and Gate protection of power semiconductor devices.	07
	(b)	What are the advantages of an SBS over a DIAC and Explain SBS firing circuit in detail.	07
Q.4	(a)	Draw and explain the operation of a single-phase Half-wave uncontrolled rectifier with Resistive Load.	07
	(b)	Explain the effect of free-wheeling diode in detail. OR	07
Q.4	(a)	Draw and explain the operation of a single-phase Full-wave uncontrolled rectifier with R-L Load.	07
	(b)	Draw and explain the operation of Three-Phase half-wave uncontrolled rectifier.	07
Q.5	(a)	Classify single-phase controlled rectifier and compare half-wave and full-wave controlled rectifier.	07
	(b)	Derive the expression of form-factor for half-wave controlled rectifier with R-L Load.	07